MOTOROLA SEMICONDUCTOR TECHNICAL DATA

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## Amplifier Transistors





## MAXIMUM RATINGS

CASE 29-04, STYLE 17 TO-92 (TO-226AA)

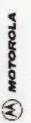
	-			
Collector - Emitter Voltage	VCEO	45	25	Vdc
Collector - Base Voltage	VCBO	20	30	Vdo
Emitter - Base Voltage	VEBO	5	5.0	Vdc
Collector Current — Continuous	ņ	8(	800	mAdo
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	0	10 cs	625 5.0	mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	O.		2	Watt mW/°C
Operating and Storage Junction Temperature Range	TJ. Tstg	-55 tc	-55 to +150	ီ -

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Chit
ermal Resistance, Junction to Ambient	ReJA	200	*C/W

ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Onit
OFF CHARACTERISTICS					100	0.00
Collector - Emitter Breakdown Voltage (IC = 10 mA, IB = 0)	BC337 BC338	V(BR)CEO	45	1.1	1.1	Vdc
Collector - Emitter Breakdown Voltage (IC = 100 µA, IE = 0)	BC337 BC338	V(BR)CES	30	11	1.1	Vdc
Emitter - Base Breakdown Voltage (IE = 10 µA, IC = 0)		V(BR)EBO	5.0	В	ľ	Vdc
Callector Cutoff Current (VCB = 30 V, IE = 0) (VCB = 20 V, IE = 0)	BC337 BC338	СВО	11	1.1	100	nAdc
Collector Cutoff Current (VCE = 45 V, VBE = 0) (VCE = 25 V, VBE = 0)	BC337 BC338	lces	1.1	1.1	100	nAdc
Emitter Cutoff Current (VEB = 4.0 V, IC = 0)		EBO	1	1	100	nAdc



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FLECTRICAL CHARACTERISTICS (TA = 25°C

Characteristic	ic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS						
DC Current Gain ((C = 100 mA, VCE = 1.0 V) ((C = 300 mA, VCE = 1.0 V)	BC337/BC338 BC337-16/BC338-16 BC337-25/BC338-25 BC337-40/BC338-40	hre.	100 100 160 250 80	11111	630 250 400 630	1
Base-Emitter On Voltage (IC = 300 mA, VCE = 1.0 V)		VBE(on)	1	ī	1.2	Vdc
Collector - Emitter Saturation Voltage (I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA)		VCE(sat)	1	1	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS	S					
Output Capacitance (VCB = 10 V, IE = 0, f = 1,0 MHz)		Cob	1	15	17.	PF.
Current-Gain — Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz)		F	1	210	10	MHZ

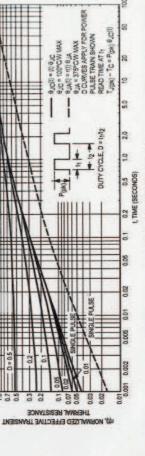
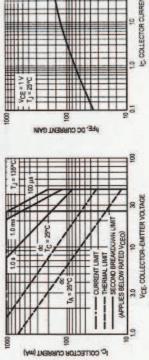
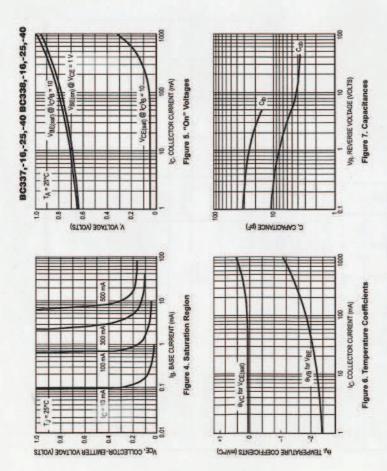


Figure 1. Thermal Response

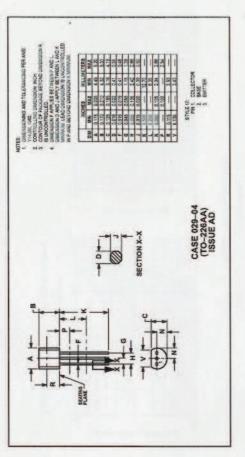


IC. COLLECTOR CURRENT (AMP) Figure 3. DC Current Gain Figure 2. Active Region — Safe Operating Area



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PACKAGE DIMENSIONS



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